University of Nebraska - Lincoln
DigitalCommons@University of Nebraska - Lincoln

Si-Hwang Liou Publications | Research Papers in Physics and Astronomy

3-1-1991

Synthesis and superconducting properties of Tl-Ba-Ca-Cu-O films

Sy_Hwang Liou
University of Nebraska-Lincoln, sliou@unl.edu

V.K. Chan
University of Nebraska - Lincoln

F. Foong
University of Nebraska - Lincoln

W.Y. Lee
University of Nebraska - Lincoln

Y.S. Gou
University of Nebraska - Lincoln

See next page for additional authors

Follow this and additional works at: http://digitalcommons.unl.edu/physicsliou

Part of the Physics Commons

Liou, Sy_Hwang; Chan, V.K.; Foong, F.; Lee, W.Y.; Gou, Y.S.; and Uen, T.M., "Synthesis and superconducting properties of Tl-Ba-Ca-Cu-O films" (1991). *Si-Hwang Liou Publications.* Paper 49.
http://digitalcommons.unl.edu/physicsliou/49

This Article is brought to you for free and open access by the Research Papers in Physics and Astronomy at DigitalCommons@University of Nebraska - Lincoln. It has been accepted for inclusion in Si-Hwang Liou Publications by an authorized administrator of DigitalCommons@University of Nebraska - Lincoln.

Authors
Sy_Hwang Liou, V.K. Chan, F. Foong, W.Y. Lee, Y.S. Gou, and T.M. Uen

This article is available at DigitalCommons@University of Nebraska - Lincoln: http://digitalcommons.unl.edu/physicsliou/49

SYNTHESIS AND SUPERCONDUCTING PROPERTIES OF Tl-Ba-Ca-Cu-O FILMS

S.H. Liou, V.K. Chan, F. Foong
Behlen Laboratory of Physics and Center for Materials Research and Analysis
University of Nebraska, Lincoln, Nebraska 68588-0111

W.Y. Lee
IBM Almaden Research Center
San Jose, California 95120-6099

Y.S. Gou and T.M. Uen
Institute of Electrophysics
National Chiao Tung University, Hsinchu, Taiwan

Abstract

The Tl-Ba-Ca-Cu-O superconducting films were synthesized by sputtering either from a single target or from two oxide targets in a symmetric configuration. Films with zero resistance T_c of up to 122 K were obtained after various post annealing treatment at 870 – 950°C under oxygen atmosphere. We have studied morphology, structure, magnetic and superconducting properties of these films. Films prepared by two different sputtering techniques have similar results which depend mostly on the film compositions and their annealing conditions. We found that the induced magnetic flux in the film decreases rapidly with increasing temperature, indicating the weak flux pinning.

Introduction

Following the initial discovery of superconductivity in the Tl-Ba-Ca-Cu-O system,[1,2] the highest T_c (R=0) at 125K has been observed in the compound of $Tl_2Ba_2Ca_2Cu_3O_{10}$ (2223)[3,4]. Thin film research on the Tl-based superconductors is particularly important because their T_c's (R=0) are much higher than those of the rare earth based $Y_1Ba_2Cu_3O_{7-x}$ compounds. Furthermore, it is likely to obtain more stable high critical current densities in excess of 10^5 - 10^6 A/cm^2 at 77K in the Tl-based system.

Recently, polycrystalline films 0.7 μm thick containing predominantly $Tl_2Ba_2Ca_1Cu_2O_8$ (2212) phase with T_c (R=0) at 97K and a transport J_c of 1.1 x 10^5 A/cm^2 at 76K have been obtained by Ginley et al.[5] using electron beam evaporation. Highly oriented films 0.4 μm thick (with the c-axis perpendicular to the film plane) containing nearly a single phase of 2212 as well as having a T_c (R=0) at 102K and a transport J_c of 1.2 x 10^5 A/cm^2 at 77K have been prepared by Ichikawa et al.[6] using RF magnetron sputtering and a single oxide target. Highly textured c-axis oriented films 2.0 - 4.0 μm thick containing both 2223 and 2212 phases with a T_c (R=0) at 120K and a J_c by magnetic measurement of 1.5 x 10^4 A/cm^2 at 77K have been reported by Lee et al.[7] using two identical oxide targets in a symmetrical RF diode sputtering system.

The ability to produce thin films with the pure high T_c $Tl_2Ba_2Ca_2Cu_3O_{10}$ phase not only can further improve J_c's at higher temperatures but may also provide a useful material for a fundamental study on the Tl-based superconducting oxides.

In this paper, we discuss the preparation conditions for films with T_c (R=0) at 122K. The results of magnetic properties of these films are presented.

Film Growth

The Tl-Ba-Ca-Cu-O films were prepared on MgO(100), Y-ZrO_2 (random orientation) and $LaAlO_3$ (100) substrates by sputtering either from a single targets or from two oxide target in a symmetric configuration. The details of the sample synthesis have been reported in our previous papers[7,8]. Due to the volatility of the Tl-oxide, the optimal processing of the Tl-based films requires good control of the Tl-vapor partial pressure. We have used two different methods to control the Tl-vapor partial pressure. One is annealing the film in a sealed gold box with a composite Tl-compound. The other one is annealing the film in a two zone-furnace, in which the Tl-vapor partial pressure is controlled by the zone temperature. The first method is much simpler and the results are reproducible. The second method requires a fine adjustment which we need to study further. The films reported here were prepared by the first method. The annealing steps have been shown to be a crucial determinant of the quality of Tl-based superconducting films[9]. In this study, we show that the films consist of nearly pure $Tl_2Ba_2Ca_2Cu_3O_{10}$ phase with T_c (R=0) in the range of 100K to 122K and c-axis perpendicular to the film plane were obtain after annealing 870 ~ 895 for up to 3 hours. The major factors that lead to achieve a higher T_c than that of the previous study are perhaps due to the better control of Tl-vapor partial pressure and annealing at higher temperature for a longer time. We also observed a substantial improvement in the superconducting properties for films subsequently annealed at low temperature (< 700°C) either in air or oxygen. The detailed study of low temperature annealing will be discussed elsewhere[10].

Composition, Structure and Processing Conditions

The film compositions were determined by x-ray fluorescence microprobe spectroscopy. A typical composition of as-deposited films is $Tl_{2.1}Ba_{2.4}Ca_{2.0}Cu_{3.1}O_x$. The composition of the as-deposited film was very homogeneous, but the composition of

Manuscript received September 24, 1990.

0018-9464/91/0300-1227$01.00 © 1991 IEEE

the post-annealed film was not homogeneous, especially the Tl and Ca content. As an example, we have tested the stability of Tl in a single crystal. As shown in Figure 1(a), a single crystal with 2223 phase was prepared on a MgO(100) substrate. After we had annealed this crystal at 800°C without providing additional Tl-vapor for 15 minute, we found that the phase of this crystal was changed, its surface became rough, and its Tl-content was lost completely. Its morphology, as shown in Figure 1(b), is completely different from the original crystal. The Tl content can vary widely depending on the annealing temperature and the duration of the annealing time at the high temperature. The amount of Ba, Ca and Cu in the annealed films was found to be insensitive to the processing conditions if we average over a large area. However, the micro-scale composition of annealed films has some variations which depend on the processing conditions. In order to investigate the effect of the processing conditions on the micro-scale composition, we have prepared two films with similar superconducting and structural properties. The morphology and the composition of

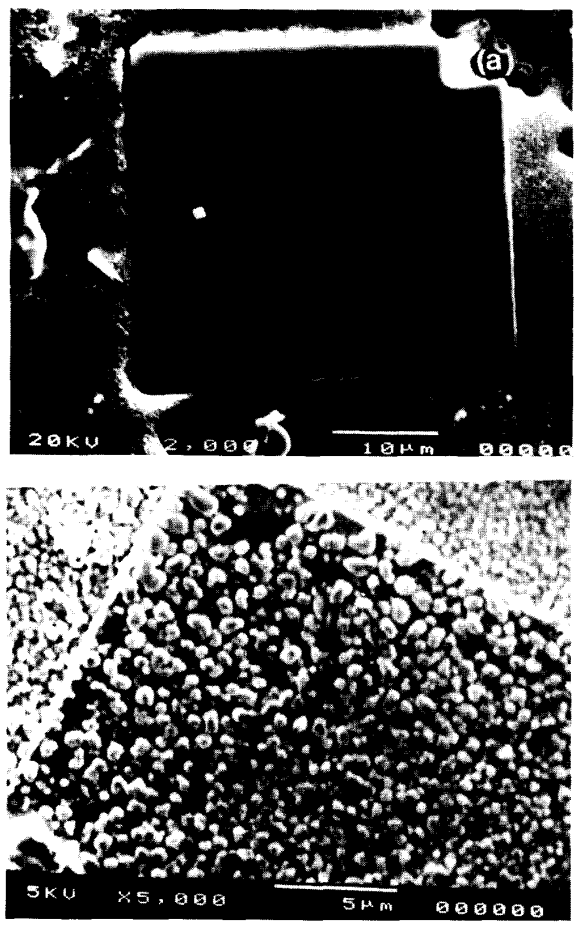

Fig. 1 Scanning electron micrographs of Tl-Ba-Ca-Cu-O film on MgO(100) (a) a single crystal with 2223 phase, (b) after annealed at 800°C without additional Tl-vapor in the gold box.

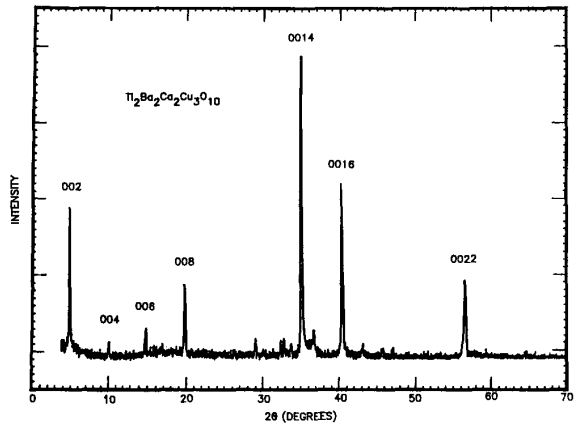

Fig. 2 X-ray (θ - 2θ scans normal to the film plane for a Tl-Ba-Ca-Cu-O film containing primarily the 2223 phase. The film is grown on a Y-ZrO_2 substrate. (The Y-ZrO_2 single crystal substrate is cut randomly and is not along (100) orientation).

the films were studied by scanning electron microscope with energy dispersive x-ray analysis. These films are highly c-axis oriented with mostly (00ℓ) peaks of $Tl_2Ba_2Ca_2Cu_3O_{10}$ phase as revealed by the x-ray diffraction pattern (as shown in Figure 2). The micrographs of films on Y-ZrO_2 substrates after annealing at 890°C for 3 hours and at 895°C for 1 hour are shown in Figures 3(a) and 3(b) respectively. The films annealed at 890°C for 3 hours had plate-like grains with many small Ca-rich grains on their surface. The film composition at different portions is marked in Figure 3(a) and is listed in Table I.

Table I. The film composition at various portions

A. Plate-like	$Tl_{1.6}Ba_{1.7}Ca_{2.0}Cu_{3.0}O_x$
B. Plate-like	$Tl_{1.5}Ba_{1.7}Ca_{2.0}Cu_{3.0}O_x$
C. Dot	$Tl_{1.2}Ba_{1.8}Ca_{3.5}Cu_{3.0}O_x$
D. Dot	$Tl_{1.3}Ba_{1.9}Ca_{4.4}Cu_{3.0}O_x$
E. Rod-like	$Tl_{2.0}Ba_{3.0}Ca_{1.1}Cu_{3.0}O_x$

The morphology of the film annealed at 895°C for 1 hour is shown in Figure 3(b). The plate-like grains were connected much closer than that of the previous film. The composition of this film is $Tl_{1.8}Ba_{1.8}Ca_{1.8}Cu_{3.0}O_x$ and it does not change from place to place. However, we still observe many submicron Ca-rich dots in the plate-like grains.

Transport, Flux Trapping, and Granularity

The superconducting and transport properties were measured by the standard four-point measurement using a dc method by switching the polarization of the applied current during the measurement. Critical current densities (J_c's) were measured in the van der pauw configuration with and without a lithographic patterning. Figure 4 shows the data of resistance versus temperature of the film annealed at 895°C for 1 hour. This

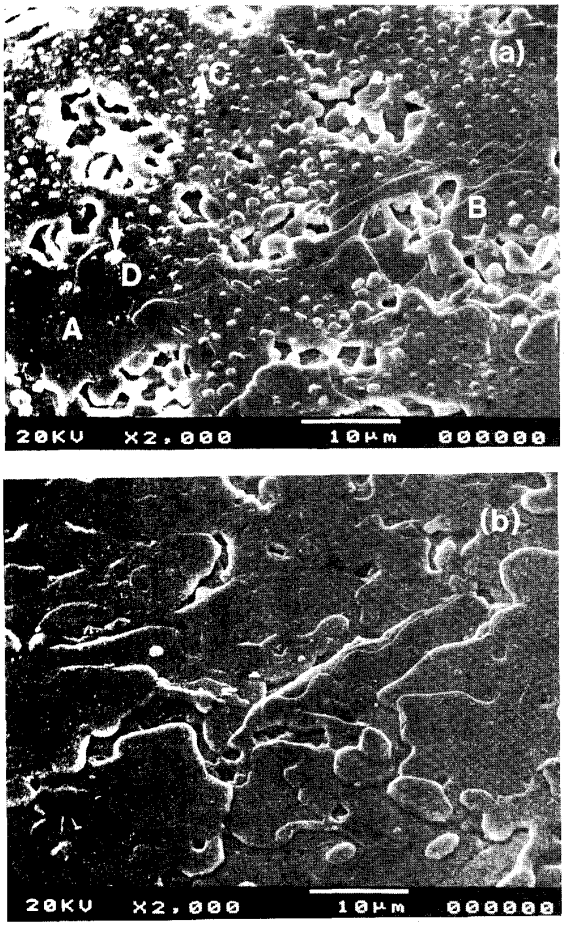

Fig. 3 Scanning electron micrographs of Tl-Ba-Ca-Cu-O films on Y-ZrO_2. (a) annealed at 890°C for 3 hours, (The composition of marked portions are listed in Table I.) (b) annealed at 895°C for 1 hour. (The white dots are the Ca-rich portions.)

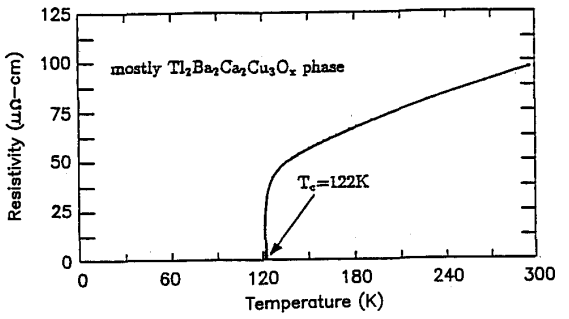

Fig. 4 A typical Resistance vs. temperature curve of the Tl-based superconducting film annealed at 895°C for 1 hour under O_2.

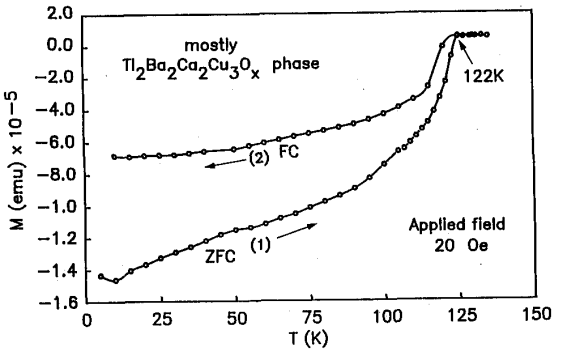

Fig. 5 The diamagnetic shielding effect (ZFC) and the Meissner effect (FC) of the Tl-based superconducting film annealed at 895°C for 1 hour under O_2.

film have a T_c onset at 130K and a T_c (R=0) at 122K. The J_c's at zero magnetic field is about 10^4 A/cm^2.

We found the superconducting transition temperature of our films with $Tl_2Ba_2Ca_2Cu_3O_{10}$ phase vary from 100K to 122K, and it is very sensitive to the processing conditions. The J_c's of the films prepared on Y-ZrO_2 and MgO substrates were in the range of $10^3 \sim 10^4$ A/cm^2 at 77K. The J_c's of the films prepared on $SrTiO_3$ and $LaAlO_3$ substrates were in the range of 10^4 A/cm$^2 \sim 10^6$ A/cm^2 at 77K.

The magnetic properties of the films were studied by using SQUID magnetometer. The diamagnetic shielding and Meissner effect data were shown in Figure 5. The diamagnetic shielding data was obtained after cooling in zero field, followed by applying a field of 20 Oe and taking data on warming. The Meissner effect data was measured on cooling in an applied field of 20 Oe. The diamagnetic shielding and Meissner signals at 6K are estimated to be 30% and 15% of those for a perfect diamagnetic of the same shape and volume, respectively. The low values of the diamagnetic shielding and the Meissner signals indicate a serious film-substrate interactions or a substantial portion of non-superconductor in the film.

Figure 6 shows a magnetization curve at 6K for the film annealed at 895°C, the applied fields were up to ±55 kOe and were perpendicular to the films' surface. Analysis of these data using the standard Bean method indicates a critical current density of 7.5 x 10^4 A/cm^2 at 6 K under 55 kOe[11]. J_c of 7.5 x 10^5 A/cm^2 at 6K and 4.2 x 10^4 A/cm^2 at 77K under zero field were obtained for this film. The flux trapping data, as shown in Figure 7, was obtained after cooling in the applied field. The induced flux in the film decrease rapidly with increasing temperature. This clearly indicates the weak flux pinning at higher temperature. The flux trapping data correspond to the J_c function of temperature at zero field. This rapid decrease in J_c, which is similar to that of some $YBa_2Cu_3O_{7-x}$ granular films, may be due to the granular nature of these films[12].

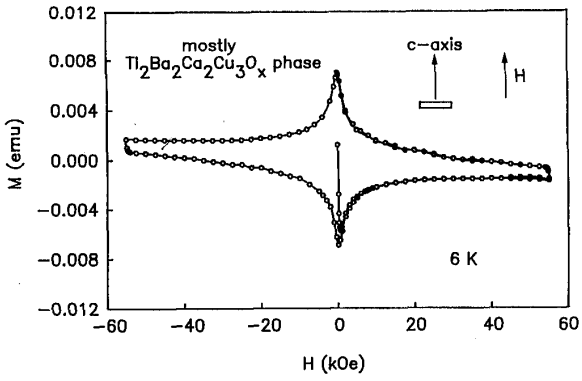

Fig. 6 Magnetization versus field curve at 6K for the film annealed at 895°C for 1 hour. The magnetic field was applied normal to the film surface.

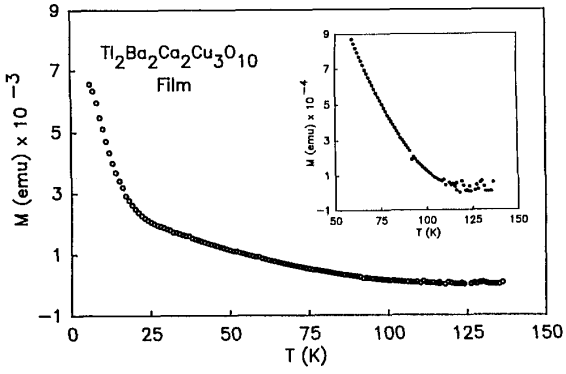

Fig. 7 Flux trapping versus temperature for the film annealed at 895°C for 1 hour. This data were obtained after cooling in the applied field of 50 kOe, removing the field and taking the data on warming in zero field.

Summary

Superconducting films of Tl-Ba-Ca-Cu-O have been prepared by sputtering. Films with zero resistance T_c of up to 122K were obtained after various post annealing at 870 ~ 895°C from 1 hour to 3 hours. The composition of films is not very homogenous in sub-micrometer scale. The critical current at 77K of the these films are in the 10^3 A/cm^2 to 10^4 A/cm^2 range, which is much smaller than that of the films prepared on $SrTiO_3$ and $LaAlO_3$ substrates. The low critical current density in these films are likely due to the granularity in these films .

* This work is supported by NASA Lewis grant NAG 3-866, the Nebraska University Foundation and the Nebraska Energy Office.

References

1. Z.Z. Sheng and A.M. Hermann, *Nature*, **332**, 138(1988).
2. R.M. Hazen, L.W. Finger, R.J. Angel, C.T. Prewitt, N.L. Ross, C.G. Hadidiacos, P.J. Heaney, D.R. Veblen, Z.Z. Sheng, A. El Ali, and A.M. Hermann, *Phys. Rev. Lett.*, **60**, 1657(1988).
3. C.C. Torardi, M.A. Subramanian, J.C. Calabrese, J. Gopalakrishnan, K.J. Morrissey, and T. Sleight, *Science*, **240**, 631(1988).
4. S.S.P. Parkin, V.Y. Lee, E.M. Engler, A.I. Nazzal, T.C. Huang, G. Gorman, R. Savoy, and R. Beyers, *Phys. Rev. Lett.*, **60**, 2539(1988).
5. D.S. Ginley, J.F. Kwak, R.P. Hellmer, R.L. Baughmen, E.L. Venturini, and B. Morosin, *Appl. Phys. Lett.*, **53**, 406(1988).
6. Y. Ichikawa, H. Adachi, K. Setsune, S. Hatta, K. Hirochi, and K. Wasa, *Appl. Phys. Lett.*, **53**, 919(1988).
7. W.Y. Lee, V.Y. Lee, J. Salem, T.C. Huang, R. Savory, D.C. Bullock, and S.S.P. Parkin, *Appl. Phys. Lett.*, **53**, 329(1988).
8. S.H. Liou, M. Hong, A.R. Kortan, J. Kwo, D.D. Bacon, C.H. Chen, R.C. Farrow, G.S. Grader, *Proc. of the Conference on the Science and Technology of Thin Film Superconductors*, Colorado Springs, Colorado 1988 edited by Robert D. McConnell and Stuart A. Wolf (Plenum, New York). p229.
9. S.H. Liou, *Proc. of Material Research Society*, Vol. 169, (1990).
10. S.H. Liou, unpublished.
11. C.P. Bean, *phys. Rev. Lett.*, **8**, 250(1962).
12. S.S. Yom, T.S. Hahn, Y.H. Kim, H. Chu and S.S. Choi, *Appl. Phys. Lett.*, **54**, 2370(1989).